

The Effects of Nanostructure on Thermoelectric Device Performance

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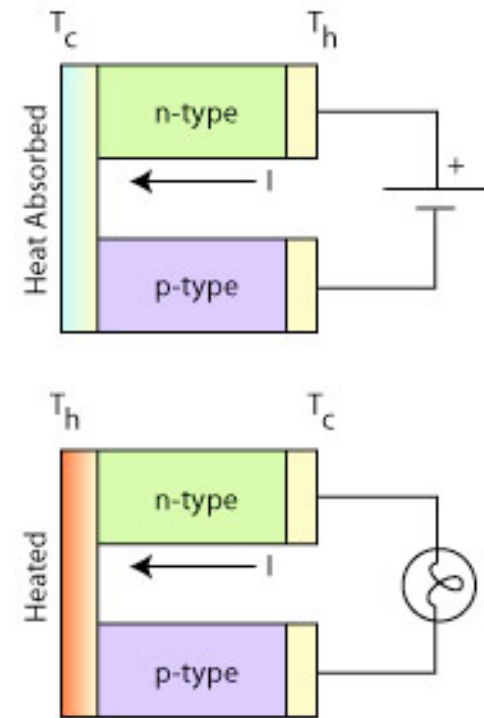
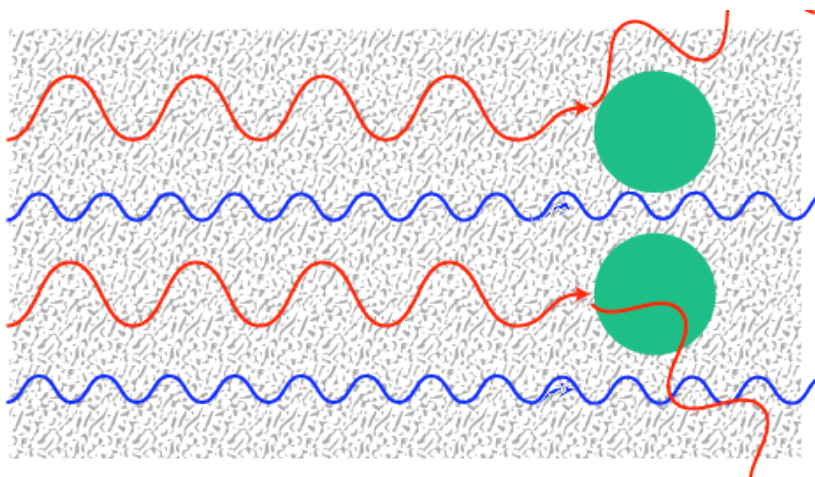


■ Figure of Merit

$$Z = \frac{\sigma \alpha^2}{\lambda_T}$$

■ Slack's Proposal

- Phonon-Glass, Electron-Crystal





Where we left off...

- Bi_2Te_3 & Bi_2Se_3 ($ZT \sim 0.8-1.0$ at 300K)
- PbTe ($ZT \sim 0.8$ at 800K)
- SiGe ($ZT \sim 0.6$ at 1000K)

- LAST ($ZT \sim 1.6$ at 650K)
- SALT ($ZT \sim 1.7$ at 700K)

- Simple Goal: Look at some of the other materials out there.



- Superlattice Thermoelectrics
- “Rattling Cage” Thermoelectrics
- Low-Dimensional Thermoelectrics

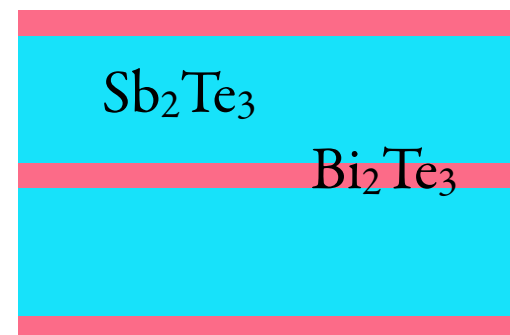
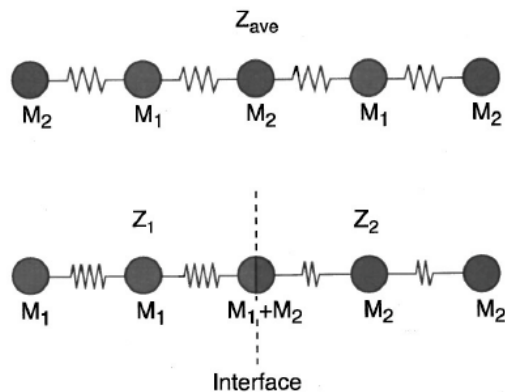


Man-Made Superlattice Thermoelectrics

■ $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ Alternating Layers

- Deposited using Metal Organic Chemical Vapor Deposition (MOCVD)
- 10 Å Bi_2Te_3 / 50 Å Sb_2Te_3
- $ZT \sim 2.4$ at 300K p-type, $ZT \sim 1.2$ for n-type

■ Phonon reflection (mind the gap)



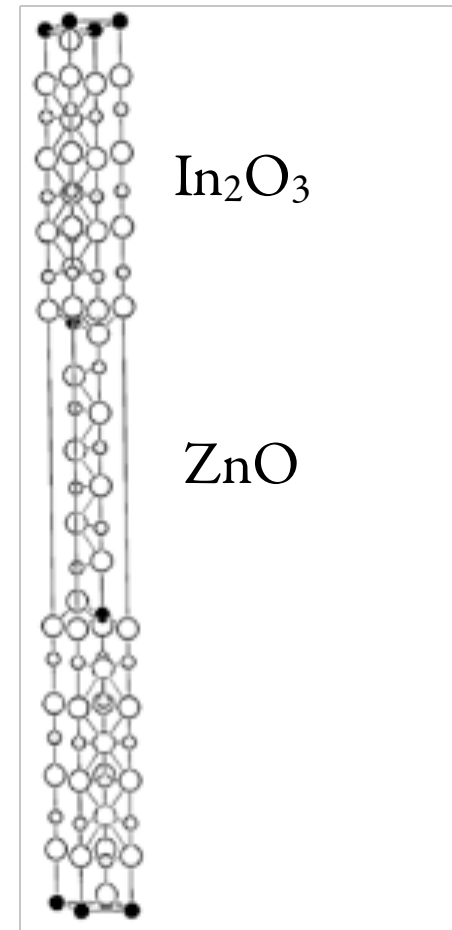
Venkatasubramanian, *Phys. Rev. B*, 2000



Nature-Made Superlattice Thermoelectrics

■ Oxides

- $(\text{SrO})_m(\text{SrTiO}_3)$
 - ✦ $ZT=0.34$ at 1000K
 - ✦ Doping with Nb or La
- $(\text{ZnO})_m(\text{In}_2\text{O}_3)$, $m=5$
 - ✦ ZnO conducts heat too well
 - Dope Mg on Zn sites or Y on In sites
- *Issues*: Need to better understand defect chemistry
- *Benefits*: Oxidation resistance, low toxicity, high thermal stability

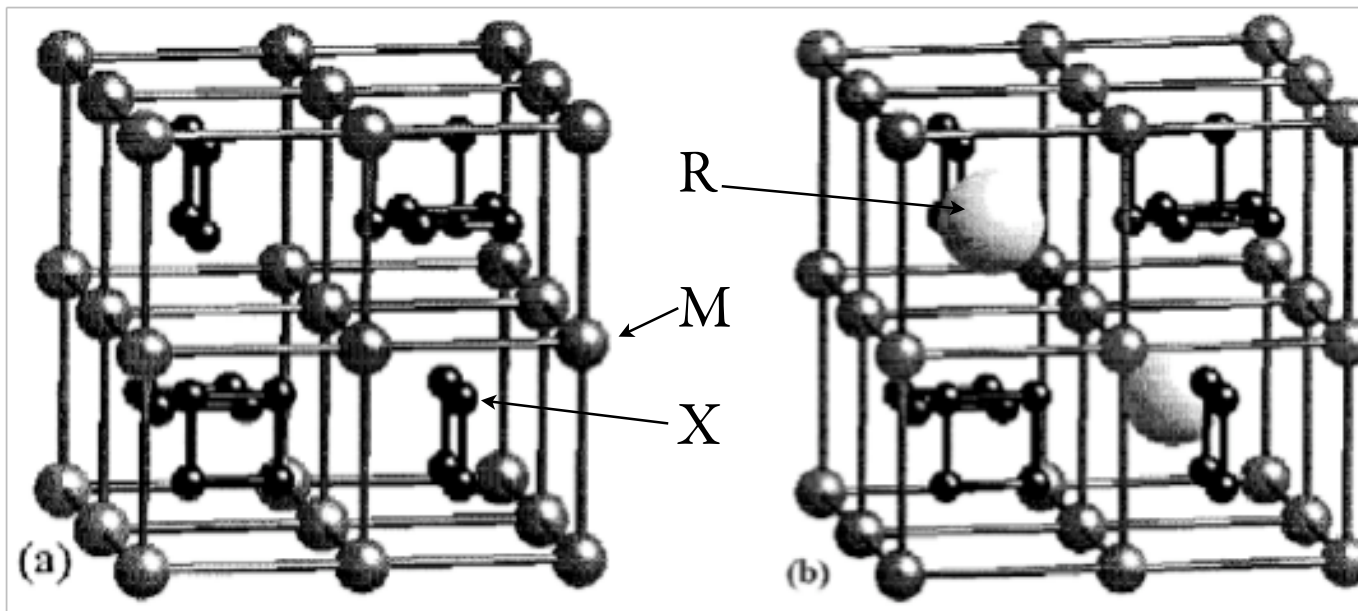
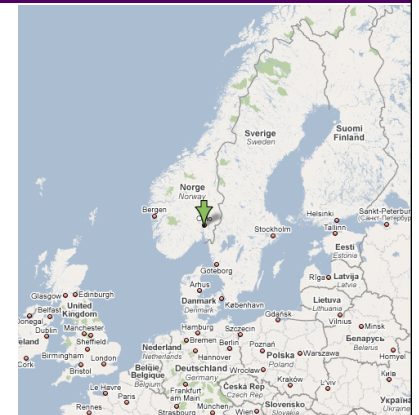




“Rattling Cage” Thermoelectrics

■ Skutterudites (cubic, $Im\bar{3}$)

- *Binary*: MX_3 (M=Co,Rh,Ir, X=P, As, Sb)
- *Ternary (filled)*: RM_4X_{12} (R= Rare earth element)
- ✦ (ZT ~ 1.8 at $\sim 900K$)



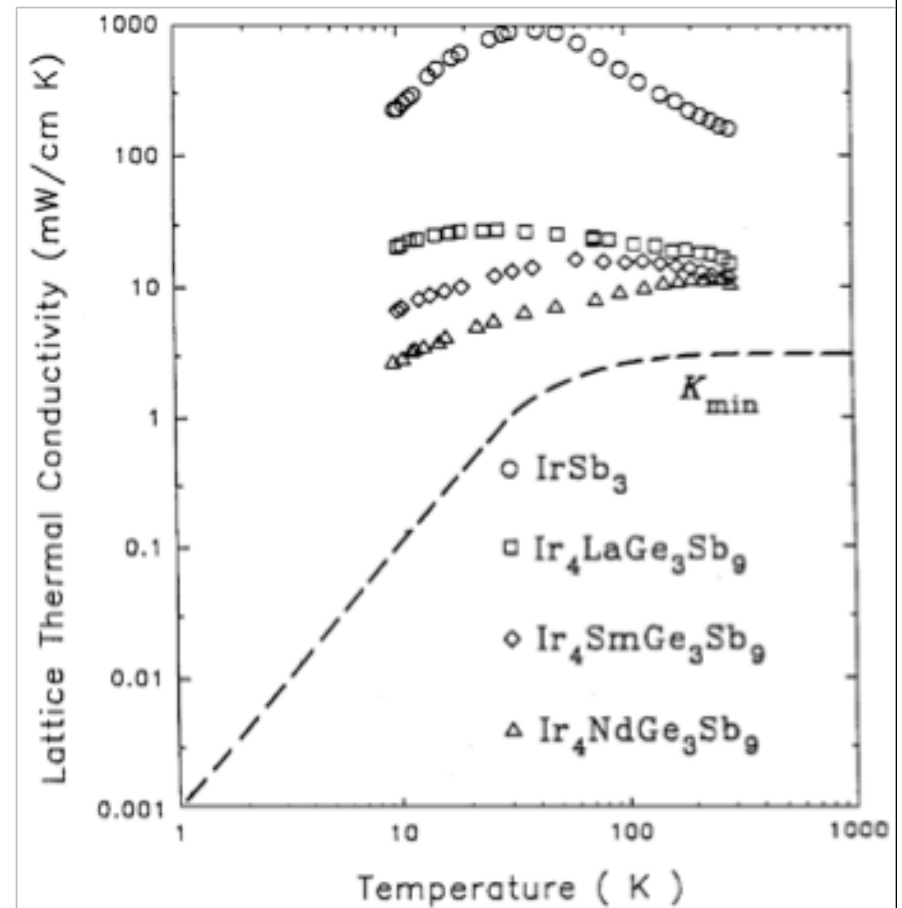
Nolas *et al.*, *J. Appl. Phys.*, 1996 || NASA Tech Briefs, 2001



“Rattling Cage” Thermoelectrics

- Example: Ternary IrSb_3
 - Rattlers: La, Sm, Nd
 - ✦ Reduce Thermal Conductivity by about an order of magnitude

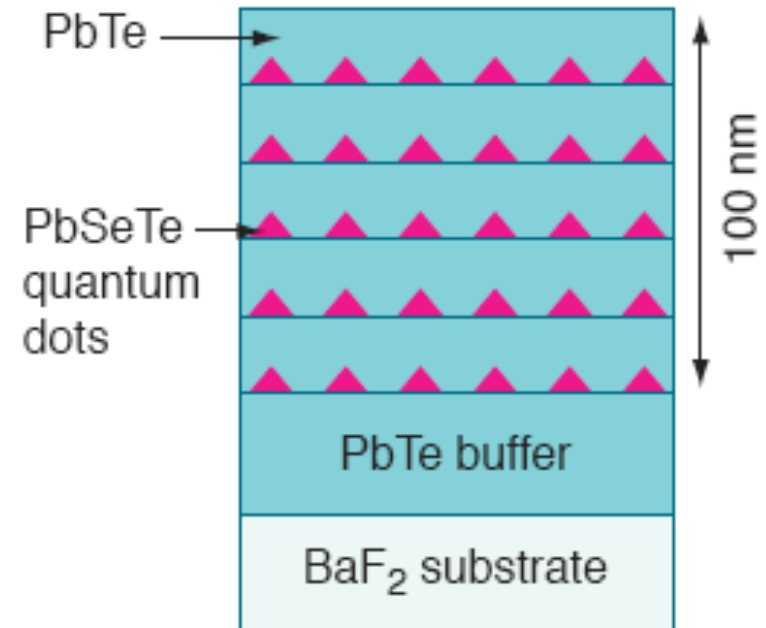
- *Benefits:* abundance, low volatility, low cost, good thermoelectric properties



Dyck et al., *Phys. Rev. B.*, 2002



- PbSeTe Quantum dot superlattice
 - Dots ~ 1 nm tend to produce an increase in ZT
 - Low dimensionality enhances Seebeck coefficient by increasing density of states near the Fermi level
 - Quantum wells create scattering interfaces for phonons





- Not just the material but also the design...
 - Contact resistances
 - Thermocouple length and number
 - Carnot Efficiencies
 - Manufacturing methods
 - ✦ Molecular beam epitaxy: slow and expensive
 - ✦ Natural nanostructuring?
 - ✦ Self-assembly?